Preferred Device

Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- Lead Formed for Surface Mount Application in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Electrically Similar to Popular D44H/D45H Series
- Low Collector Emitter Saturation Voltage
 - $V_{CE(sat)} = 1.0$ Volt Max @ 8.0 Amperes
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb–Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	80	Vdc
Emitter–Base Voltage	V _{EB}	5	Vdc
Collector Current – Continuous – Peak	Ι _C	8 16	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	20 0.16	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ extsf{ heta}JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	R_{\thetaJA}	71.4	°C/W
Lead Temperature for Soldering	ΤL	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



ON Semiconductor®

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SILICON POWER TRANSISTORS 8 AMPERES 80 VOLTS, 20 WATTS





xH11G

Y	=	Year
WW	=	Work Week
J4xH11	=	Device Code
		x = 4 or 5
G	=	Pb–Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage $(I_C = 30 \text{ mA}, I_B = 0)$		V _{CEO(sus)}	80	-	-	Vdc
Collector Cutoff Current (V_{CE} = Rated V_{CEO} , V_{BE} = 0)		I _{CES}	-	-	10	μΑ
Emitter Cutoff Current (V _{EB} = 5 Vdc)		I _{EBO}	-	-	50	μΑ
ON CHARACTERISTICS			•	•		•
Collector–Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.4 \text{ Adc})$		V _{CE(sat)}	-	-	1	Vdc
Base-Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc})$		V _{BE(sat)}	-	-	1.5	Vdc
DC Current Gain (V _{CE} = 1 Vdc, I _C = 2 Adc)		h _{FE}	60	-	-	-
DC Current Gain (V _{CE} = 1 Vdc, I _C = 4 Adc)			40	-	-	
DYNAMIC CHARACTERISTICS				-	-	-
Collector Capacitance (V _{CB} = 10 Vdc, f _{test} = 1 MHz)	MJD44H11 MJD45H11	C _{cb}		130 230		pF
Gain Bandwidth Product (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 20 MHz)	MJD44H11 MJD45H11	fT		50 40		MHz
SWITCHING TIMES						
Delay and Rise Times (I _C = 5 Adc, I _{B1} = 0.5 Adc)	MJD44H11 MJD45H11	t _d + t _r		300 135		ns
Storage Time ($I_C = 5$ Adc, $I_{B1} = I_{B2} = 0.5$ Adc)	MJD44H11 MJD45H11	t _s		500 500		ns
Fall Time (I _C = 5 Adc, I _{B1} = I _{B2} = 0.5 Adc	MJD44H11 MJD45H11	t _f		140 100		ns

ORDERING INFORMATION

Device	Package Type	Package	Shipping [†]		
MJD44H11	DPAK				
MJD44H11G	DPAK (Pb–Free)	369C			
MJD44H11-001	DPAK-3		75 Units / Rail		
MJD44H11-001G	DPAK-3 (Pb-Free)	369D			
MJD44H11RL	DPAK				
MJD44H11RLG	DPAK (Pb–Free)		1800 Tape & Reel		
MJD44H11T4	DPAK				
MJD44H11T4G	DPAK (Pb-Free)	0000	2500 Tape & Reel		
MJD44H11T5	DPAK	- 369C			
MJD44H11T5G	DPAK (Pb–Free)				
MJD45H11	DPAK				
MJD45H11G	DPAK (Pb-Free)				
MJD45H11-001	DPAK-3		75 Units / Rail		
MJD45H11-001G	DPAK-3 (Pb-Free)	369D			
MJD45H11RL	DPAK				
MJD45H11RLG	DPAK (Pb–Free)	369C	1800 Tape & Reel		
MJD45H11T4	DPAK	3090			
MJD45H11T4G	DPAK (Pb–Free)		2500 Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



Figure 1. Thermal Response





There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.







PACKAGE DIMENSIONS





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.22	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.180 BSC		4.58 BSC		
н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
ĸ	0.102	0.114	2.60	2.89	
L	0.090 BSC		2.29 BSC		
R	0.180	0.215	4.57	5.45	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
٧	0.035	0.050	0.89	1.27	
Ζ	0.155		3.93		

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS



DPAK-3 CASE 369D-01

Ζ



	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
۷	0.035	0.050	0.89	1.27
Ζ	0.155		3.93	

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. FMITTER

COLLECTOR 4.

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